

UNISONIC TECHNOLOGIES CO., LTD

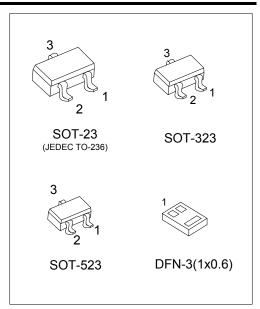
MMBT2222A

NPN SILICON TRANSISTOR

NPN GENERAL PURPOSE AMPLIFIER

■ FEATURES

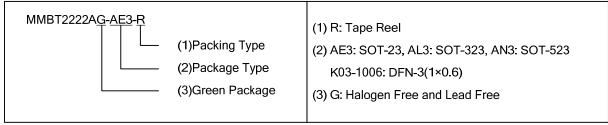
* This device is for use as a medium power amplifier and switch requiring collector currents up to 600mA.



ORDERING INFORMATION

Ordering Number	Doolsono	Pin Assignment			Doolsins	
	Package	1	2	3	Packing	
MMBT2222AG-AE3-R	SOT-23	Е	В	С	Tape Reel	
MMBT2222AG-AL3-R	SOT-323	Е	В	С	Tape Reel	
MMBT2222AG-AN3-R	SOT-523	Е	В	С	Tape Reel	
MMBT2222AG-K03-1006-R	DFN-3(1×0.6)	В	E	С	Tape Reel	

Note: Pin Assignment: E: Emitter B: Base C: Collector



MARKING

SOT-23 / SOD-323 / SOD-523	DFN-3(1×0.6)
日 1P.G 日 日	• MG

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■ ABSOLUTE MAXIMUM RATINGS (T_A=25°C, unless otherwise specified.)

PARAMETER		SYMBOL	RATINGS	UNIT	
Collector-Base Voltage		V_{CBO}	75	V	
Collector-Emitter Voltage		V_{CEO}	40	V	
Emitter-Base Voltage		V_{EBO}	6	V	
Collector Current		I _C	600	mA	
Collector Dissipation	SOT-23	Pc	350		
	SOT-323		200		
	SOT-523		150	mW	
	DFN-3(1×0.6)		300 (Note 1)		
Junction Temperature	nction Temperature		+150	°C	
Storage Temperature		T _{STG}	-55 ~ +150	°C	

Note: Absolute maximum ratings are the values beyond which the device will be damaged permanently.

Absolute maximum ratings are only stress ratings and it is not implied for functional device operation.

■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient SOT-23 SOT-323 SOT-523 DFN-3(1×0.6)		357		
	SOT-323	Δ	625	°C/W
	SOT-523	θ_{JA}	833	
	DFN-3(1×0.6)		416 (Note)	

Note: Transistor mounted on an FR4 printed circuit board.

■ ELECTRICAL CHARACTERISTICS (Ta=25°C, unless otherwise specified.)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV_CBO	I _C =10μA, I _E =0 75				V
Collector-Emitter Breakdown Voltage	BV_CEO	I _C =10mA, I _B =0	40			V
Emitter-Base Breakdown Voltage	BV_{EBO}	$I_E = 10 \mu A, I_C = 0$	6			V
	I _{CBO}	V _{CB} =60V, I _E =0			0.01	μΑ
Collector Cutoff Current		V _{CB} =60V, I _E =0, Ta=150°C			10	μΑ
Emitter Cutoff Current	I_{EBO}	V_{EB} =3.0V, I_{C} =0			10	nA
Base Cutoff Current	I_{BL}	V_{CE} =60V, $V_{EB(OFF)}$ =3.0V			20	nA
Collector Cutoff Current	I_{CEX}	V_{CE} =60V, $V_{EB(OFF)}$ =3.0V			10	nA
ON CHARACTERISTICS						
		I _C =0.1mA, V _{CE} =10V	35			
		I _C =1.0mA, V _{CE} =10V	50			
		I _C =10mA, V _{CE} =10V	75			
DC Current Gain	h_{FE}	I _C =10mA, V _{CE} =10V, Ta= -55°C	35			
		I _C =150mA, V _{CE} =10V(Note)	100		300	
		I _C =150mA, V _{CE} =1.0V(Note)	50			
		I _C =500mA, V _{CE} =10V(Note)	40			
Collector-Emitter Saturation		I _C =150mA, I _B =15mA			0.3	V
Voltage(Note)	$V_{CE(SAT)}$	I _C =500mA, I _B =50mA			1.0	V
Base-Emitter Saturation	\/	I _C =150mA, I _B =15mA	0.6		1.2	V
Voltage(Note)	$V_{BE(SAT)}$	I _C =500mA, I _B =50mA			2.0	V
SMALL SIGNAL CHARACTERISTIC	S		_			
Real Part of Common-Emitter High Frequency Input Impedance	Re(hje)	I _C =20mA, V _{CB} =20V, f=300MHz			60	Ω
Transition Frequency	f⊤	I _C =20mA, V _{CE} =20V, f=100MHz	300			MHz
Output Capacitance	Cobo	V _{CB} =10V, I _E =0, f=100kHz			8.0	pF
Input Capacitance	Cibo	V _{EB} =0.5V, I _C =0, f=100kHz			25	pF
Collector Base Time Constant	rb'Cc	I _C =20mA, V _{CB} =20V, f=31.8MHz			150	pS
Noise Figure	NF	I _C =100μA, V _{CE} =10V, Rs=1.0kΩ f=1.0kHz		4.0	dB	
SWITCHING CHARACTERISTICS		•		•		
Delay Time	t_D	V _{CC} =30V, V _{BE(OFF)} =0.5V,			10	ns
Rise Time	t _R	I _C =150mA, I _{B1} =15mA			25	ns
Storage Time	ts	Vcc=30V, I _C =150mA			225	ns
Fall Time	t _F	I _{B1} = I _{B2} =15mA			60	ns

Note: Pulse test: Pulse Width $\leq 300 \mu s, \ Duty \ Cycle \leq 2.0\%$

■ TEST CIRCUITS

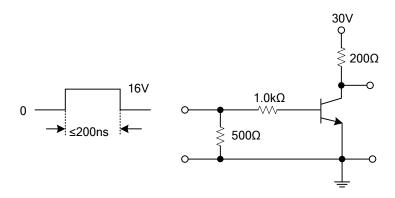


Fig 1. Saturated Turn-On Switching Time

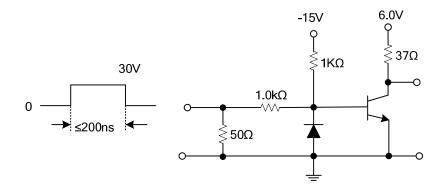
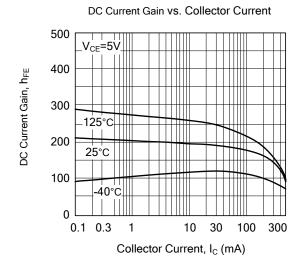
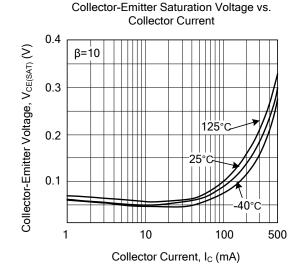
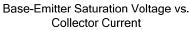


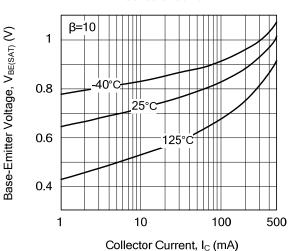
Fig 2. Saturated Turn-Off Switching Time

■ TYPICAL CHARACTERISTICS

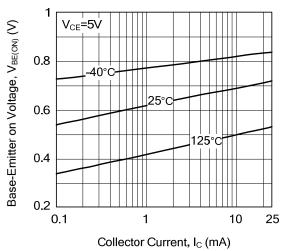




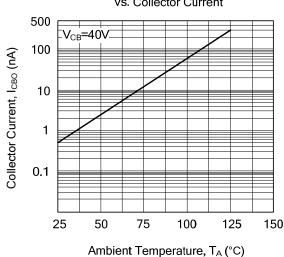




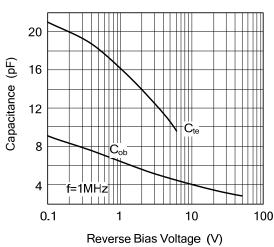
Base-Emitter on Voltage vs. Collector Current



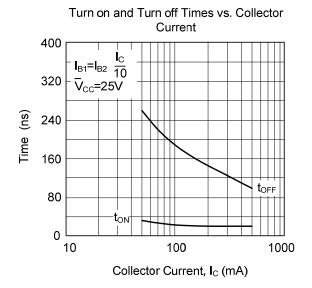
Base-Emitter Saturation Voltage vs. Collector Current

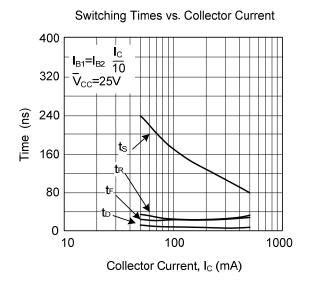


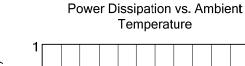
Emitter Transition and Output Capacitance vs. Reverse Bias Voltage

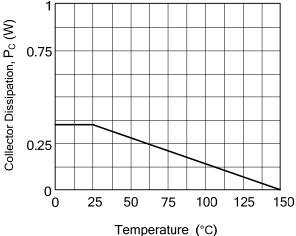


■ TYPICAL CHARACTERISTICS(Cont.)









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